

CSM212N6S23

20V N-Channel Enhancement Mode MOSFET

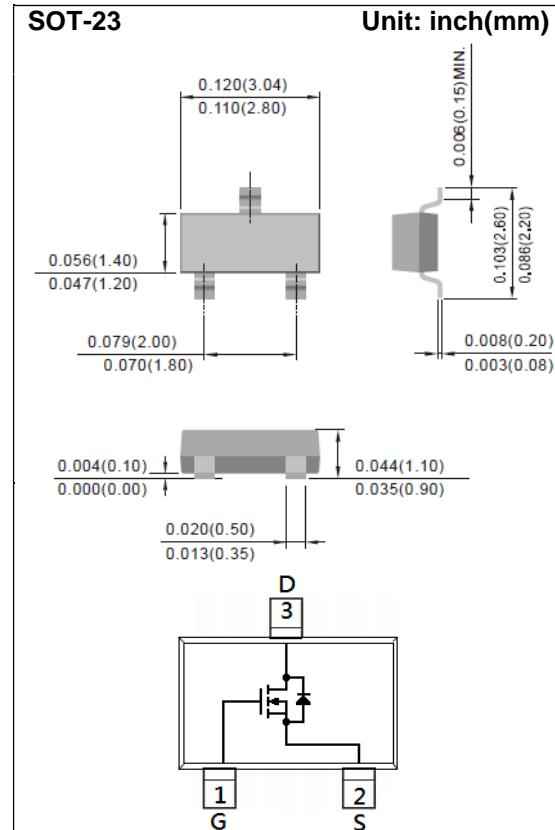
Voltage 20 V Current 6.0A

Features

- $R_{DS(ON)}$, $V_{GS} @ 4.5V$, $I_D @ 6.0A < 25m\Omega$
- $R_{DS(ON)}$, $V_{GS} @ 2.5V$, $I_D @ 4.8A < 36m\Omega$
- $R_{DS(ON)}$, $V_{GS} @ 1.8V$, $I_D @ 3.5A < 45m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc

Mechanical Data

- Case : SOT-23 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0003 ounces, 0.0084 grams



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	± 12	
Continuous Drain Current	I_D	6.0	A
Pulsed Drain Current	I_{DM}	16.4	
Power Dissipation	P_D	1.25	W
		10	mW/ $^\circ C$
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55~150	$^\circ C$
Typical Thermal Resistance - Junction to Ambient ^(Note 3)	$R_{\theta JA}$	100	$^\circ C/W$

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Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$\text{V}_{\text{GS}}=0\text{V}, \text{I}_D=250\mu\text{A}$	20	-	-	V
Gate Threshold Voltage	$\text{V}_{\text{GS(th)}}$	$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}, \text{I}_D=250\mu\text{A}$	0.4	0.66	1.2	
Drain-Source On-State Resistance	$\text{R}_{\text{DS(on)}}$	$\text{V}_{\text{GS}}=4.5\text{V}, \text{I}_D=6.0\text{A}$	-	21	25	$\text{m}\Omega$
		$\text{V}_{\text{GS}}=2.5\text{V}, \text{I}_D=4.8\text{A}$	-	30	36	
		$\text{V}_{\text{GS}}=1.8\text{V}, \text{I}_D=3.5\text{A}$	-	36	45	
Zero Gate Voltage Drain Current	I_{DSS}	$\text{V}_{\text{DS}}=20\text{V}, \text{V}_{\text{GS}}=0\text{V}$	-	-	1	μA
Gate-Source Leakage Current	I_{GSS}	$\text{V}_{\text{GS}}=\pm 12\text{V}, \text{V}_{\text{DS}}=0\text{V}$	-	-	± 100	nA
Dynamic <small>(Note 5)</small>						
Total Gate Charge	Q_g	$\text{V}_{\text{DS}}=10\text{V}, \text{I}_D=6.0\text{A}, \text{V}_{\text{GS}}=4.5\text{V}$ <small>(Note 1,2)</small>	-	4.6	-	nC
Gate-Source Charge	Q_{gs}		-	0.8	-	
Gate-Drain Charge	Q_{gd}		-	1	-	
Input Capacitance	C_{iss}	$\text{V}_{\text{DS}}=10\text{V}, \text{V}_{\text{GS}}=0\text{V}, \text{f}=1\text{MHz}$	-	350	-	pF
Output Capacitance	C_{oss}		-	40	-	
Reverse Transfer Capacitance	Crss		-	29	-	
Turn-On Delay Time	$\text{td}_{(\text{on})}$	$\text{V}_{\text{DD}}=10\text{V}, \text{I}_D=6.0\text{A}, \text{V}_{\text{GS}}=4.5\text{V}, \text{R}_G=6\Omega$ <small>(Note 1,2)</small>	-	4	-	ns
Turn-On Rise Time	tr		-	47	-	
Turn-Off Delay Time	$\text{td}_{(\text{off})}$		-	18	-	
Turn-Off Fall Time	tf		-	10	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_s	---	-	-	1.5	A
Diode Forward Voltage	V_{SD}	$\text{I}_s=1\text{A}, \text{V}_{\text{GS}}=0\text{V}$	-	0.75	1.2	V

NOTES :

1. Pulse width $\leq 300\mu\text{s}$, Duty cycle $\leq 2\%$.
2. Essentially independent of operating temperature typical characteristics.
3. R_{JJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.
5. Guaranteed by design, not subject to production testing.

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TYPICAL CHARACTERISTIC CURVES

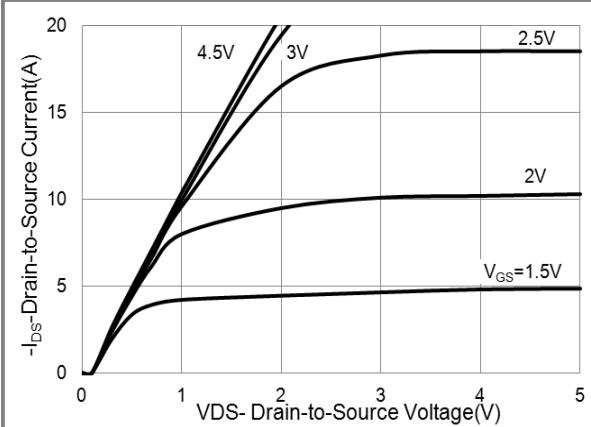


Fig.1 On-Region Characteristics

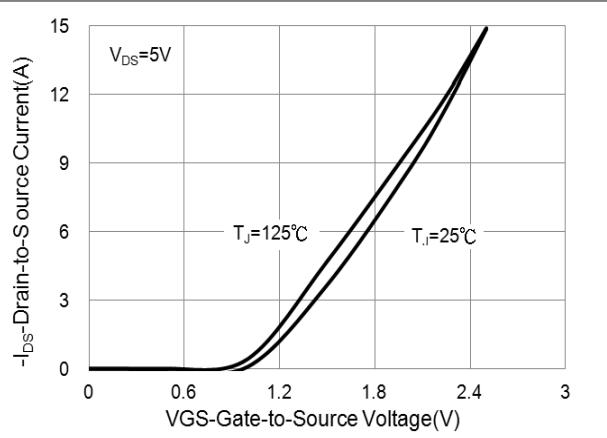


Fig.2 Transfer Characteristics

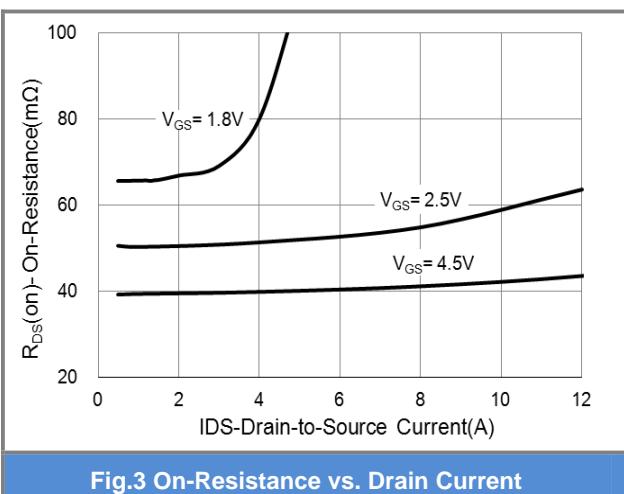


Fig.3 On-Resistance vs. Drain Current

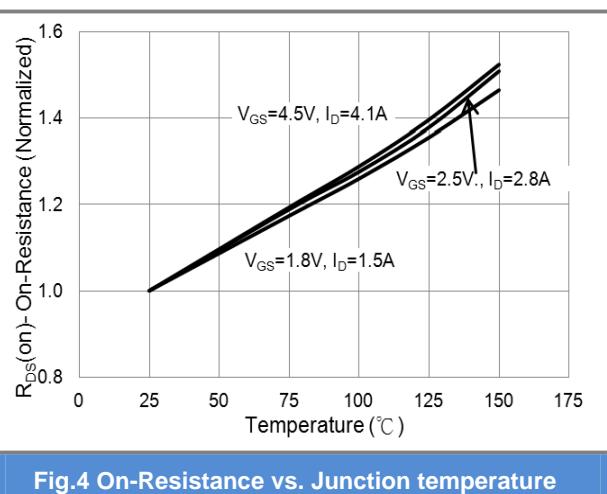


Fig.4 On-Resistance vs. Junction temperature

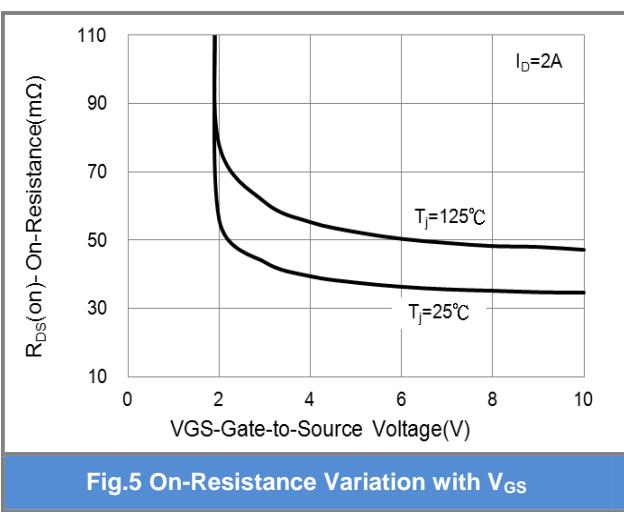


Fig.5 On-Resistance Variation with V_G

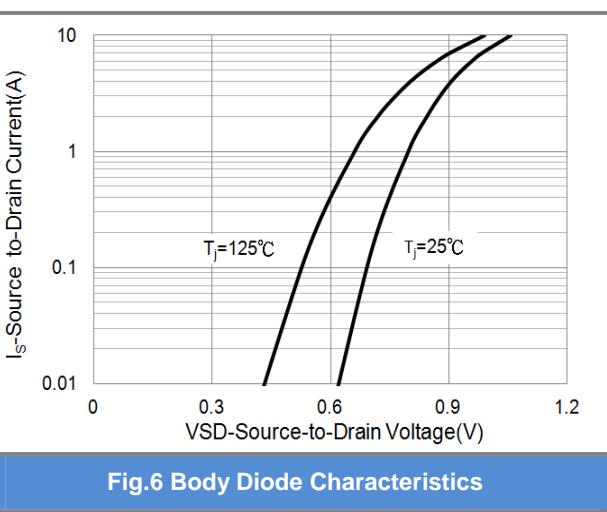
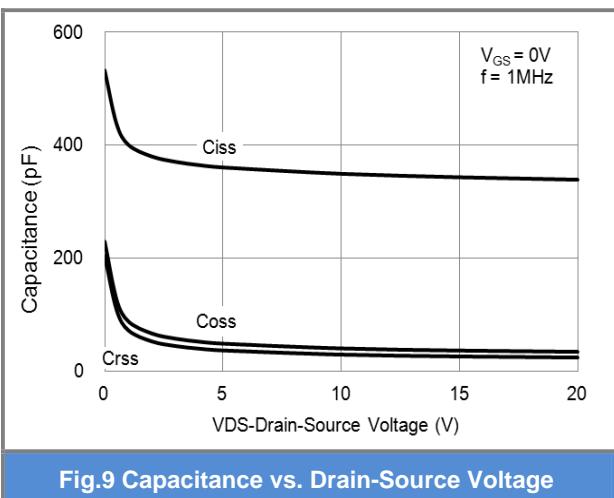
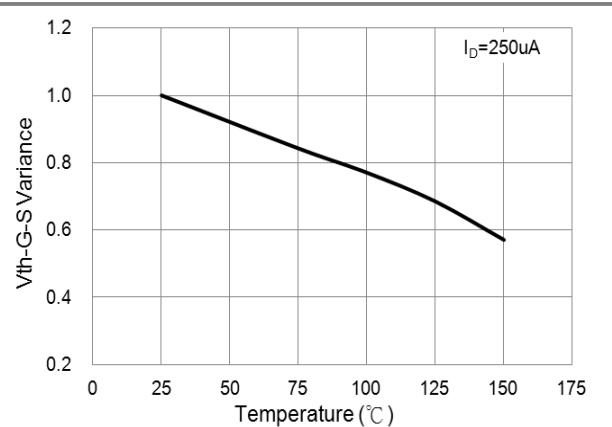
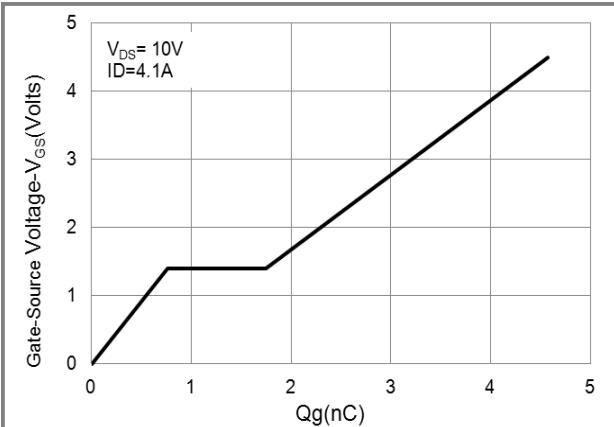


Fig.6 Body Diode Characteristics

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TYPICAL CHARACTERISTIC CURVES

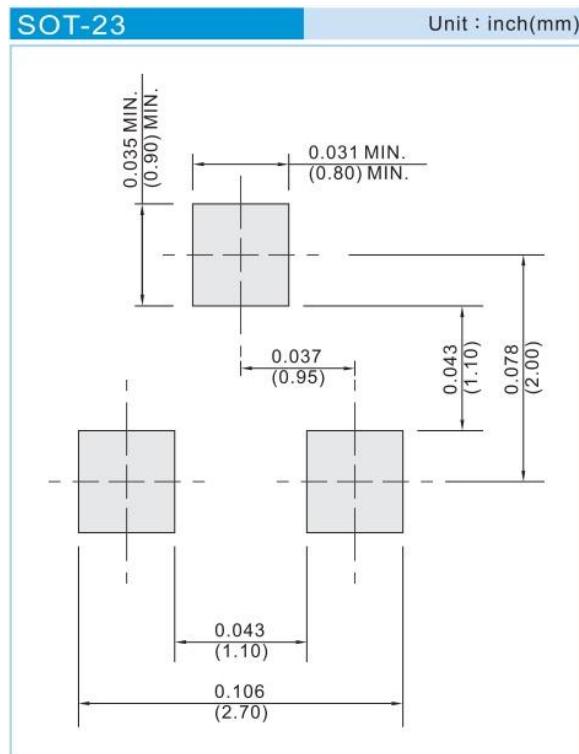


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Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
CSM212N6S23	SOT-23	3K pcs / 7" reel		Halogen free

Mounting Pad Layout



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